NSN 5961-01-110-3359

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-110-3359 **Inclosure Material:** Plastic **Overall Length:** Between 0.390 inches and 0.420 inches **Overall Height:** Between 0.160 inches and 0.190 inches **Overall Width:** Between 0.325 inches and 0.355 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 collector to emitter voltage/static/base open and 500.0 collector to emitter reverse voltage, with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No